

Features

- Protection of Battery Cell Reverse Connection without External load
- Over-temperature Protection
- Overcharge Current Protection
- Two-step Overcurrent Detection: Over Discharge Current Load Short Circuiting
- Charger Detection Function
- 0V Battery Charging Function

Applications

- One-Cell Li-ion Battery Pack
- Power Bank

- 50mΩ Low R_{SS(ON)} Internal Power MOSFET
- Delay Times are generated inside
- High-accuracy Voltage Detection
- Low Current Consumption
 Operation Mode: 3.9μA typ.
 Power-down Mode: 2.2μA typ.
- Only One External Capacitor Required
- Available in SOT23/SOT23-3 Package
- -40°C to +85°C Temperature Range
- One-Cell Li-poly Battery Pack
- IOT Sensor/Electronic Toys/ Wearable Devices

General Description

The RY2200 is a high integration solution for lithium-ion/polymer battery protection. RY2200 contains internal power MOSFET, high-accuracy voltage detection circuits and delay circuits. RY2200 has all the protection functions required in the battery application including overcharging, over discharging, overcurrent and load short circuiting protection etc. The accurate overcharging detection voltage ensures safe and full utilization charging. The low standby current drains little current from the cell while in storage. The device is not only targeted for digital cellular phones, but also for any other Li-Ion and Li-Poly battery-powered information appliances requiring long-term battery life.

The RY2200 requires a minimal number of readily available, external components and is available in a space saving SOT23/SOT23-3 package.

Typical Application Circuit

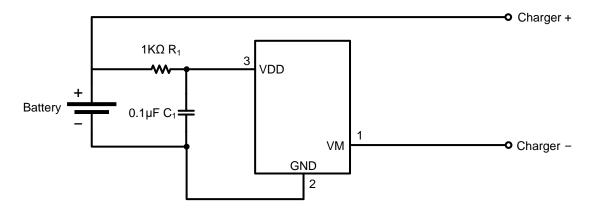


Figure 1. Typical Application Circuit



Pin Description

Pin Configuration

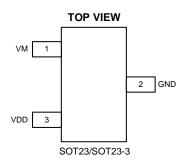


Figure 2. Pin Configuration

Pin Description

Pin	Name	Function			
1	VM	Charger minus voltage input pin			
2	GND	Grounding end, battery core negative pole			
3	VDD	Power Supply Pin			

Order Information (1)

Marking	Part No.	Model	VCU (V)	VCL (V)	VDL (V)	VDR (V)	T/R Qty
MJ <u>YLL</u>	70702029	RY2200	4.3±50mV	4.1±50mV	2.4±100mV	3.0±100mV	3000 PCS
M8 <u>YLL</u>	70702069	RY2200At3	4.3±50mV	4.1±50mV	2.8±100mV	3.0±100mV	3000 PCS
M3 <u>YLL</u>	70702053	RY2200A	4.3±50mV	4.1±50mV	2.8±100mV	3.0±100mV	3000 PCS
M4 <u>YLL</u>	70702054	RY2200B	4.425±50mV	4.1±50mV	2.8±100mV	3.0±100mV	3000 PCS

Note (1): All RYCHIP parts are Pb-Free and adhere to the RoHS directive.



Specifications

Absolute Maximum Ratings (1) (2)

Item	Min	Max	Unit
VDD Input Voltage	-0.3	6	V
VM Input Voltage	-6	10	V
Operating Temperature Range	-40	85	°C
Operating junction temperature, T _J	-40	150	°C
Storage temperature, T _{stg}	-55	150	°C
Lead Temperature (Soldering, 10sec.)		260	°C

Note (1): Exceeding these ratings may damage the device.

Note (2): The device is not guaranteed to function outside of its operating conditions.

ESD Ratings

Item	Description	Value	Unit
	Human Body Model (HBM)		
$V_{(ESD\text{-}HBM)}$	ANSI/ESDA/JEDEC JS-001-2014	±2000	V
	Classification, Class: 2		
	Charged Device Mode (CDM)		
V _(ESD-CDM)	ANSI/ESDA/JEDEC JS-002-2014	±200	V
	Classification, Class: C0b		
	JEDEC STANDARD NO.78E APRIL 2016		
I _{LATCH-UP}	Temperature Classification,	±150	mA
	Class: I		

Thermal Information

Item	Description	Value	Unit
$R_{ heta JA}$	Junction-to-ambient thermal resistance (1)(2)	220	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	99	°C/W
$R_{ heta m JB}$	Junction-to-board thermal resistance	79	°C/W
Ψлт	Junction-to-top characterization parameter	7	°C/W
Ψјв	Junction-to-board characterization parameter	80	°C/W

Note (1): The package thermal impedance is calculated in accordance to JESD 51-7.

Note (2): Thermal Resistances were simulated on a 4-layer, JEDEC board.



Electrical Characteristics (1)

Parameter	Symbol	Test Condition	Test Conditions		Тур.	Max	Unit
Detection Current							
			RY2200	2.7	3.2	4.4	A
			RY2200At3	0.6	0.95	1.3	
Overcharge Current Detection	$*I_{CU}$	$V_{DD}=3.6V$	RY2200A	0.6	0.95	1.3	
			RY2200B	0.6	0.95	1.3	
			RY2200	2.7	3.2	4.4	
	do T		RY2200At3	0.6	0.95	1.3	1 .
Overdischarge Current1 Detection	*I _{IOV1}	$V_{DD}=3.6V$	RY2200A	0.6	0.95	1.3	Α
			RY2200B	0.6	0.95	1.3	
Load Short-Circuiting Detection	*I _{SHORT}	V _{DD} =3.6V		10	20	30	A
Current Consumption				•			•
Current Consumption in Operation	I _{OPE}	V _{DD} =3.6V			3.9	6	μΑ
Comment Comment in in an armony		VM=0V					
Current Consumption in power Down	I_{PDN}	V _{DD} =2.0V			2.2	4	μΑ
VM Internal Resistance		VM floating					
v W Internal Resistance		V _{DD} =3.6V					
Resistance between VM and V _{DD}	*R _{VMD}	V _{DD} =3.0V VM=1.0V		100	150	200	kΩ
Desistante la desarra VM au d'OND	ψD	V _{DD} =2.0V		_	10	20	1-0
Resistance between VM and GND	*R _{VMS}	VM=1.0V		5	10	20	kΩ
FET on Resistance							
Equivalent FET on Registance	*R _{SS(ON)}	$V_{DD}=3.6V$		40	50	80	mΩ
Equivalent FET on Resistance	KSS(ON)	I _{VM} =1.0A		40	30	80	
Over Temperature Protection		_					
Over Temperature Protection	*T _{SHD+}				130		°C
Over Temperature Recovery Degree	*T _{SHD} -				100		°C
Detection Delay Time		_					
Overcharge Voltage Detection	t_{CU}			80	120	200	mS
Delay Time	icu			00	120	200	ms
Overdischarge Voltage Detection	$t_{ m DL}$			30	80	120	mS
Delay Time	UDL			30	00	120	ms
Overcharge Current Detection Delay Time	*t _{CU}			5	10	20	mS
Overdischarge Current Detection	*t _{IOV}	$V_{DD}=3.6V$		5	10	20	mS
Delay Time	*10 v	י ט.ט י 			10		1110
Load Short-Circuiting Detection Delay Time	*t _{SHORT}			100	200	400	μS

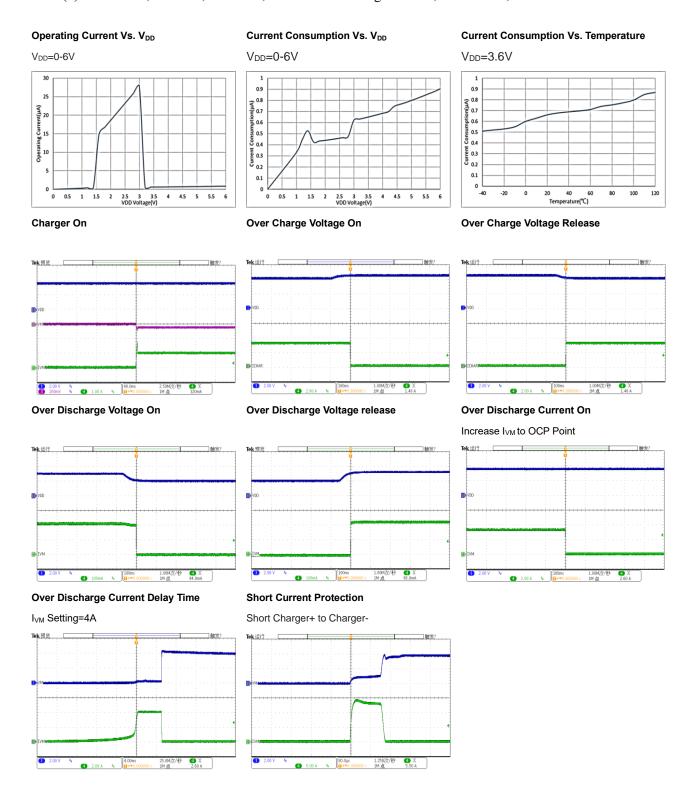
Note (1): *The parameter is guaranteed by design.



Typical Performance Characteristics (1) (2)

Note (1): Performance waveforms are tested on the evaluation board.

Note (2): $V_{DD} = 3.6V$, $R_1 = 1K\Omega$, $C_1 = 0.1uF$, 3.2A Over Discharge Current, $T_A = +25^{\circ}C$, unless otherwise noted.







Functional Block Diagram

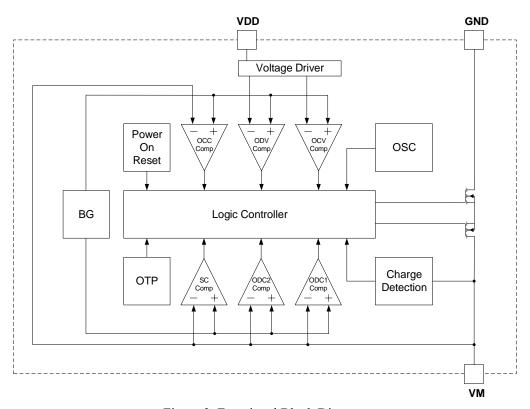


Figure 3. Functional Block Diagram

Functions Description

The RY2200 monitors the voltage and current of a battery and protects it from being damaged due to overcharge voltage, over discharge voltage, over discharge current, and short circuit conditions by disconnecting the batter from the load or charger. These functions are required in order to operate the battery cell within specified limits.

The device requires only one external capacitor. The MOSFET is integrated and its $R_{SS(ON)}$ is as low as $50m\Omega$ typical.

Normal operating mode

If no exception condition is detected, charging and discharging can be carried out freely. This condition is called the normal operating mode.

Overcharge Status

When the battery voltage becomes higher than the overcharge detection voltage (V_{CU}) during charging under normal condition and the state continues for the overcharge detection delay time (t_{CU}) or longer, the RY2200 turns the charging control FET off to stop charging. This condition is called the overcharge status. The overcharge condition is released in the following two cases:

- 1. When the battery voltage drops below the overcharge release voltage (V_{CL}), the RY2200 turns the charging control FET on and returns to the normal condition.
- 2. When a load is connected and discharging starts, the RY2200 turns the charging control FET on and returns to the normal condition. The release mechanism is as follows: the discharging current flows through an internal parasitic diode of the charging FET immediately after a load is connected and discharging starts, and the VM pin voltage increases about 0.7V (forward voltage of the diode) from the GND pin voltage momentarily. The RY2200



detects this voltage and releases the overcharge condition. Consequently, in the case that the battery voltage is equal to or lower than the overcharge detection voltage (V_{CU}), the RY2200 returns to the normal condition immediately, but in the case the battery voltage is higher than the overcharge detection voltage (V_{CU}), the chip does not return to the normal condition until the battery voltage drops below the overcharge detection voltage (V_{CU}) even if the load is connected. In addition, if the VM pin voltage is equal to or lower than the overcurrent 1 detection voltage when a load is connected and discharging starts, the chip does not return to the normal condition.

Remark If the battery is charged to a voltage higher than the overcharge detection voltage (VCU), and even if a large load causing an overcurrent is connected, the battery voltage will not fall below the overcharge detection voltage (VCU), and the overcurrent or load short detection will be detected in the battery. It does not work until the voltage is lower than the overcharge detection voltage (VCU). However, since the internal impedance of the actual battery has several tens of $m\Omega$, and the battery voltage immediately drops after the connection of the heavy load causing the overcurrent, the overcurrent operates. The load short-circuit detection works properly regardless of the battery voltage.

Over-discharge Status

When the battery voltage drops below the over-discharge detection voltage (V_{DL}) during discharging under normal condition and it continues for the over-discharge detection delay time (t_{DL}) or longer, the RY2200 turns the discharging control FET off and stops discharging. This condition is called over-discharge status. After the discharging control FET is turned off, the VM pin is pulled up by the R_{VMD} resistor between VM and VDD in RY2200. Meanwhile when VM is bigger than 1.5V (typ.) (the load short-circuiting detection voltage), the current of the chip is reduced to the power-down current (I_{PDN}). This condition is called power-down condition. The VM and VDD pins are shorted by the R_{VMD} resistor in the IC under the over-discharge and power-down conditions. The power-down condition is released when a charger is connected and the potential difference between VM and VDD becomes 1.3V (typ.) or higher (load short-circuiting detection voltage). At this time, the FET is still off. When the battery voltage becomes the over-discharge detection voltage (V_{DL}) or higher (see note), the RY2200 turns the FET on and changes to the normal condition from the over-discharge condition.

Remark If the VM pin voltage is not less than the charger detection voltage (VCHA) and the battery voltage reaches the over-discharge release voltage (VDR) or higher, the over-discharge condition is released when the battery under over-discharge condition is connected to the charger (The discharge control FET is turned on).

Overcurrent Status

When the discharging current becomes equal to or higher than a specified value (the VM pin voltage is equal to or higher than the overcurrent detection voltage) during discharging under normal condition and the state continues for the overcurrent detection delay time or longer, the RY2200 turns off the discharging control FET to stop discharging. This condition is called overcurrent status. (The overcurrent includes overcurrent, or load shortcircuiting.) The VM and GND pins are shorted internally by the R_{VMS} resistor under the overcurrent condition. When a load is connected, the VM pin voltage equals the VDD voltage due to the load. The overcurrent condition returns to the normal condition when the load is released and the impedance between the B+ and B- pins becomes higher than the automatic recoverable impedance. When the load is removed, the VM pin goes back to the GND potential since the VM pin is shorted the GND pin with the R_{VMS} resistor. Detecting that the VM pin potential is lower than the overcurrent detection voltage (V_{IOV}), the IC returns to the normal condition.



Abnormal Charge Current Detection

the VM pin voltage drops below the charger detection voltage (V_{CHA}) during charging under the normal condition and it continues for the overcharge detection delay time (t_{CU}) or longer, the RY2200 turns the charging control FET off and stops charging. This action is called abnormal charge current detection. Abnormal charge current detection works when the discharging control FET is on and the VM pin voltage drops below the charger detection voltage (V_{CHA}). When an abnormal charge current flows into a battery in the overdischarge condition, the RY2200 consequently turns the charging control FET off and stops charging after the battery voltage becomes the overdischarge detection voltage and the overcharge detection delay time (t_{CU}) elapses.

Abnormal charge current detection is released when the voltage difference between VM pin and GND pin becomes lower than the charger detection voltage (V_{CHA}) by separating the charger. Since the 0V battery charging function has higher priority than the abnormal charge current detection function, abnormal charge current may not be detected by the product with the 0V battery charging function while the battery voltage is low.

Load Short-circuiting Status

If voltage of VM pin is equal or below short-circuiting protection voltage (V_{SHORT}), the RY2200 will stop discharging and battery is disconnected from load. The maximum delay time to switch current off is t_{SHORT} . This status is released when voltage of VM pin is higher than short protection voltage (V_{SHORT}), such as when disconnecting the load.

Delay Circuits

The detection delay time for over-discharge current and load short-circuiting starts when over-discharge current is detected. As soon as over-discharge current or load short-circuiting is detected over detection delay time for over-discharge current or load short-circuiting, the RY2200 stops discharging. When battery voltage falls below over-discharge detection voltage due to over-discharge current, the RY2200 stop discharging by over-discharge current detection. In this case the recovery of battery voltage is so slow that if battery voltage after over-discharge voltage detection delay time is still lower than over-discharge detection voltage, the RY2200 shifts to power-down.

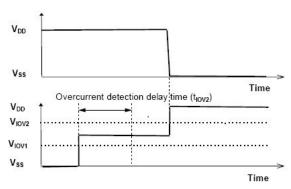


Figure 4. Overcurrent delay time



0V Battery Charging Function (1) (2) (3)

This function enables the charging of a connected battery whose voltage is 0V by self-discharge. When a charger having 0V battery start charging charger voltage (V_{0CHA}) or higher is connected between B+ and B- pins, the charging control FET gate is fixed to VDD potential. When the voltage between the gate and the source of the charging control FET becomes equal to or higher than the turn-on voltage by the charger voltage, the charging control FET is turned on to start charging. At this time, the discharging control FET is off and the charging current flows through the internal parasitic diode in the discharging control FET. If the battery voltage becomes equal to or higher than the overdischarge release voltage (V_{DU}), the normal condition returns.

Note (1): Some battery providers do not recommend charging of completely discharged batteries. Please refer to battery providers before the selection of 0V battery charging function.

Note (2): The 0V battery charging function has higher priority than the abnormal charge current detection function. Consequently, a product with the 0V battery charging function charges a battery and abnormal charge current cannot be detected during the battery voltage is low (at most 1.8V or lower).

Note (3): When a battery is connected to the IC for the first time, the IC may not enter the normal condition in which discharging is possible. In this case, set the VM pin voltage equal to the GND voltage (short the VM and GND pins or connect a charger) to enter the normal condition.

Timing Chart

Overcharge and overdischarge detection

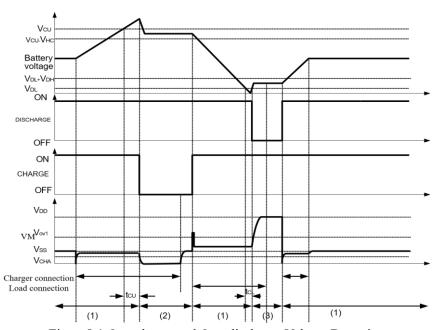


Figure 5-1 Overcharge and Overdischarge Voltage Detection

Remark:

- (1) Normal condition (2) Overcharge voltage condition
- (3) Overdischarge voltage condition (4) Overcurrent condition

Overdischarge current detection



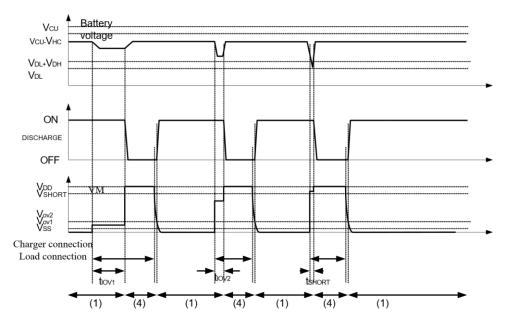


Figure 5-2 Overdischarge Current Detection

Remark:

- (1) Normal condition (2) Overcharge voltage condition
- (3) Overdischarge voltage condition (4) Overcurrent condition

Charger Detection

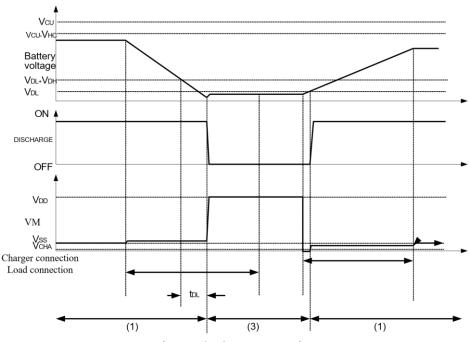


Figure 5-3 Charger Detection

Remark:

- (1) Normal condition (2) Overcharge voltage condition
- (3) Overdischarge voltage condition (4) Overcurrent condition

Abnormal Charger Detection



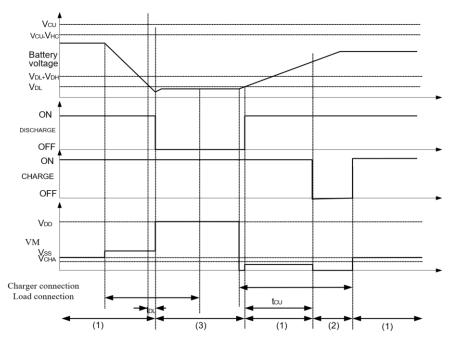


Figure 5-4 Abnormal Charger Detection

Remark:

- (1) Normal condition (2) Overcharge voltage condition
- (3) Overdischarge voltage condition (4) Overcurrent condition

Typical Application

As shown in Figure 1, the bold line is the high-density current path which must be kept as short as possible. For thermal management, ensure that these trace widths are adequate.C1& R1 is a decoupling capacitor & resistor which should be placed as close as possible to RY2200.

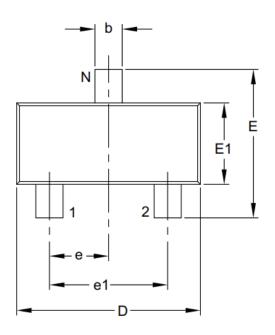
Precautions

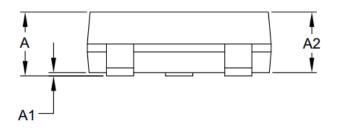
- Pay attention to the operating conditions for input/output voltage and load current so that the power loss in RY2200 does not exceed the power dissipation of the package.
- Do not apply an electrostatic discharge to this RY2200 that exceeds the performance ratings of the built-in electrostatic protection circuit.

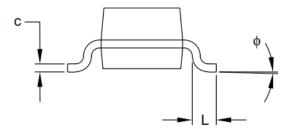


Package Description

SOT23

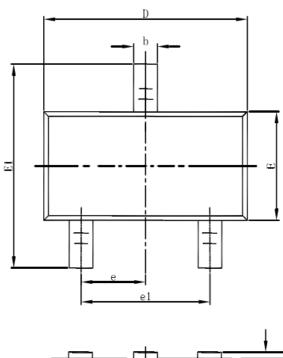


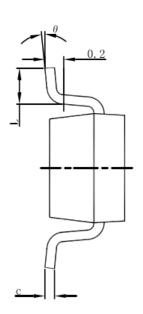


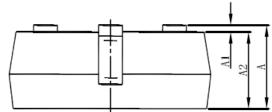


Units		MILLIMETERS		
	Dimension Limits		NOM	MAX
Number of Pins	N	3		
Lead Pitch	е		0.95 BSC	
Outside Lead Pitch	e1		1.90 BSC	
Overall Height	Α	0.89	_	1.12
Molded Package Thickness	A2	0.79	0.95	1.02
Standoff	A1	0.01	_	0.10
Overall Width	Е	2.10	_	2.64
Molded Package Width	E1	1.16	1.30	1.40
Overall Length	D	2.67	2.90	3.05
Foot Length	L	0.13	0.50	0.60
Foot Angle	ф	0°	_	10°
Lead Thickness	С	0.08	_	0.20
Lead Width	b	0.30	_	0.54









Cumbal	Dimensions Ir	n Millimeters	Dimensions	In Inches
Symbol	Min	Max	Min	Max
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
Е	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
е	0.950(BSC)		0.037(BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°